

# Low VF Schottky Barrier Rectifiers

**Comchip**  
SMD Diode Specialist

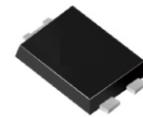
## CDBHA30100LR-HF

Reverse Voltage: 100V

Forward Current: 30A

RoHS Device

Halogen Free



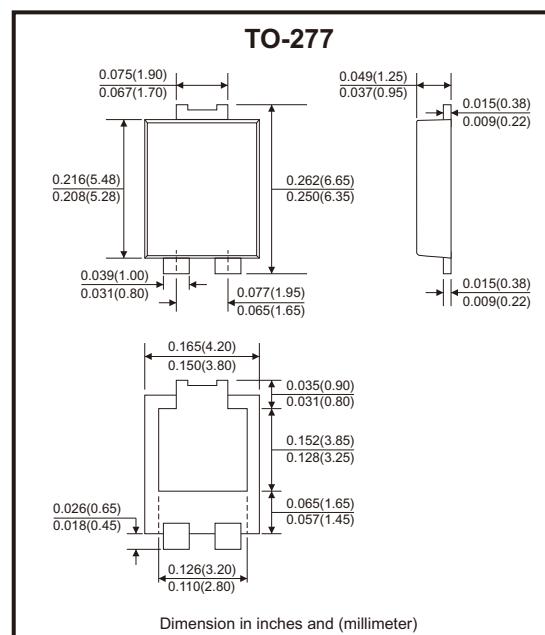
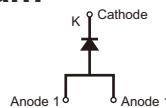
### Features

- Metal silicon junction, majority carrier conduction.
- Guard ring for overvoltage protection.
- Low power loss, high efficiency.
- High current capability, low forward voltage drop.
- High surge capability.
- Ideal for automated placement.

### Mechanical data

- Case: TO-277B, molded plastic.
- Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026.
- Mounting position: Any.

### Circuit Diagram



### Maximum Ratings (at $T_A=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	100	V
Maximum average forward rectified current	$I_{F(AV)}$	30	A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated $T_L$ )	$I_{FSM}$	200	A
Typical thermal resistance (Note 1)	$R_{\theta JA}(\text{Note 2})$	60	$^{\circ}\text{C/W}$
	$R_{\theta JL}$	3	
Operating junction temperature range	$T_J$	-55 to +150	$^{\circ}\text{C}$
Storage temperature range	$T_{STG}$	-55 to +150	$^{\circ}\text{C}$

Notes: 1. Units mounted on recommended PCB 1 oz. Pad layout.

2. The heat generated must be less than thermal conductivity from junction to ambient:  $dPD/dTJ < 1/R_{\theta JA}$ .

### Electrical Characteristics (at $T_A=25^\circ\text{C}$ , unless otherwise noted)

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Unit	
Instantaneous forward voltage (Note 1)	$T_J = 25^\circ\text{C}$	$V_F$	$I_F = 30\text{A}$	0.75	0.77	V	
			$I_F = 10\text{A}$	0.54			
			$I_F = 5\text{A}$	0.47			
	$T_J = 125^\circ\text{C}$		$I_F = 30\text{A}$	0.73			
			$I_F = 10\text{A}$	0.51			
			$I_F = 5\text{A}$	0.40			
Reverse current (Note 2)	$V_R = 100\text{V}$	$I_R$	$T_A = 25^\circ\text{C}$	30	100	$\mu\text{A}$	
			$T_A = 100^\circ\text{C}$	5		mA	
			$T_A = 125^\circ\text{C}$	20			
Typical junction capacitance	$V_R = 4\text{V}, f = 1\text{MHz}$	$C_J$		1200		pF	

Notes: 1. Pulse test: 300μs pulse width, 1% duty cycle.

2. Pulse test: pulse width ≤ 40ms.

REV:A

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## Rating and Characteristics Curves (CDBHA30100LR-HF)

Fig.1 - Forward Current Derating Curve

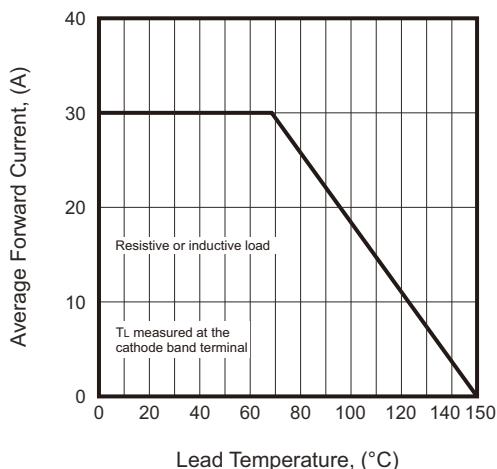


Fig.2 - Maximum Non-Repetitive Peak Forward Surge Current

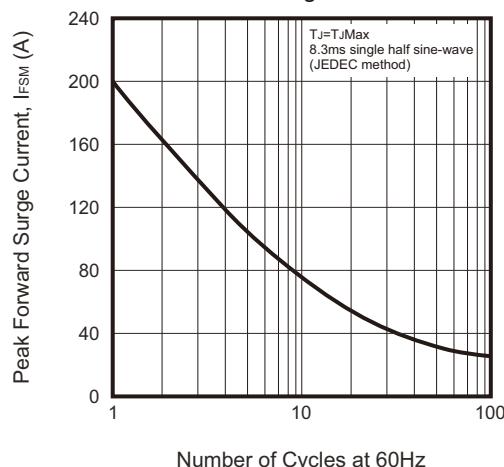


Fig.3 - Typical Instantaneous Forward Characteristics

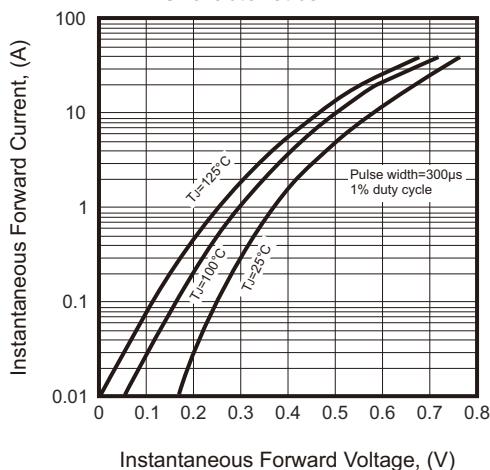


Fig.4 - Typical Reverse Characteristics

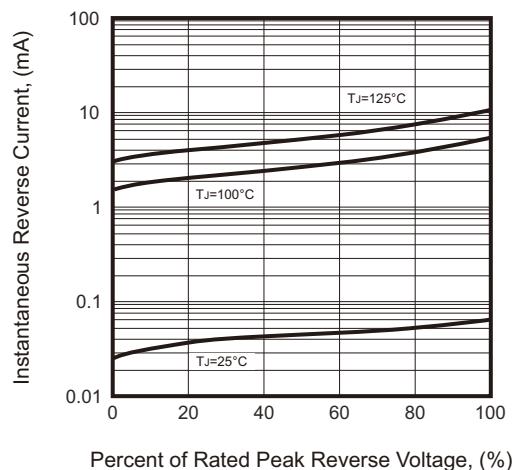
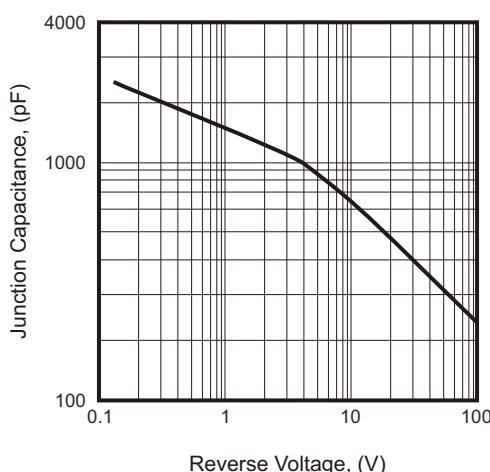
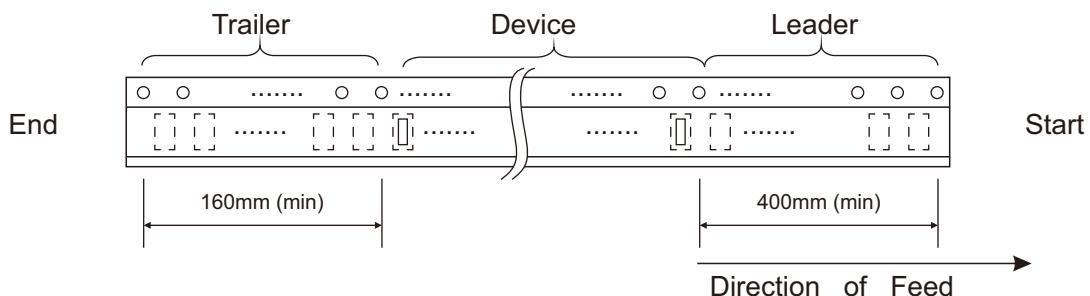
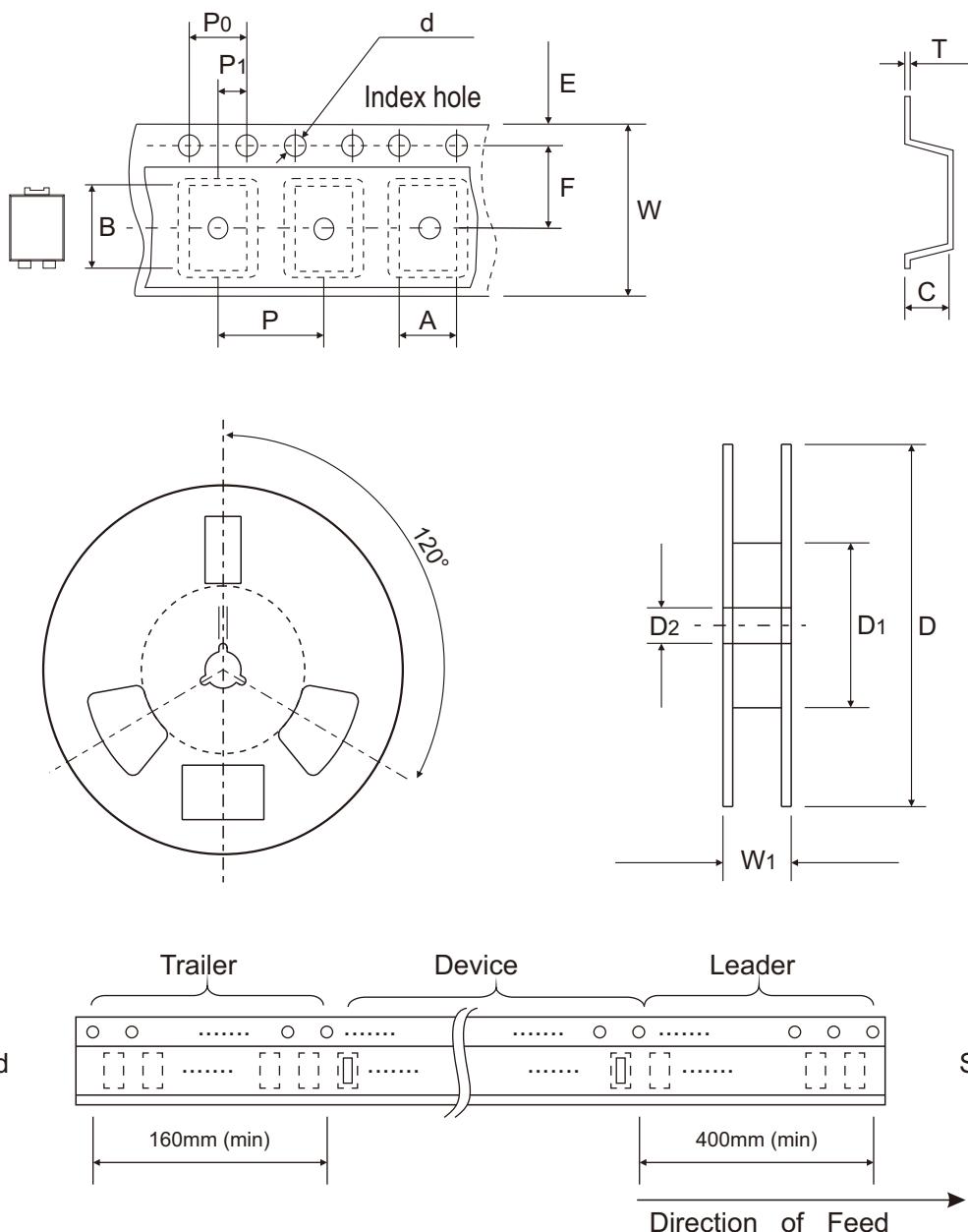


Fig.5 - Typical Junction Capacitance



## Reel Taping Specification



TO-277B	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	$4.38 \pm 0.10$	$6.90 \pm 0.10$	$4.00 \pm 0.10$	$1.55 \pm 0.05$	$330 \pm 2.00$	$75.00 \pm 1.00$	$13.30 \pm 0.30$
	(inch)	$0.172 \pm 0.004$	$0.272 \pm 0.004$	$0.157 \pm 0.004$	$0.061 \pm 0.002$	$12.992 \pm 0.079$	$2.953 \pm 0.039$	$0.524 \pm 0.012$

TO-277B	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	$1.75 \pm 0.10$	$7.50 \pm 0.10$	$8.00 \pm 0.07$	$4.00 \pm 0.07$	$2.00 \pm 0.07$	$0.30 \pm 0.05$	$16.00 \pm 0.20$	$16.40 \pm 0.50$
	(inch)	$0.069 \pm 0.004$	$0.295 \pm 0.004$	$0.315 \pm 0.003$	$0.157 \pm 0.003$	$0.079 \pm 0.003$	$0.012 \pm 0.002$	$0.630 \pm 0.008$	$0.646 \pm 0.020$